

4-CHANNEL LOW CAPACITANCE ESD PROTECTION DIODES ARRAY

The S-LRC1043-04DT1G is a 4-channel ultra low capacitance rail clam ESD protection diodes array . Each channel consists of a pair of diodes that steer positive or negative ESD current to either the positive or negative rail . A zener diode is integrated in to the array between the positive and negative supply rails. In the typical applications, the negative rail pin (assigned as GND) is connected with system ground . The Positive ESD current is steered to the ground through an ESD diode and Zener diode and the positive ESD voltage is clamped to the zener voltage.

The S-LRC1043-04DT1G is idea to protect high speed data lines.

APPLICATIONS

1) HDMI / DVI ports 2)Display Port interface 3)10M / 100M / 1G Ethernet 4)USB 2.0 interface 4)VGA interface 5)Set-top box 6)Flat panel Monitors / TVs 7)PC / Note book

FEATURES

1) 4 channels of ESD protection; 2)Provides ESD protection to IEC61000-4-2 level 4

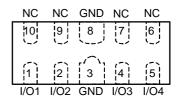
- ±15kV air discharge
- ±10kV contact discharge;
- 3) Channel I/O to GND capacitance: 0.65pF(Max)
- 4) Channel I/O to I/O capacitance: 0.6pF(Max)
- 5) Low clamping voltage;
- 6) Low operating voltage;
- 7) Improved zener structure;
- 8) Optimized package for easy high speed data lines PCB layout;
- 9) RoHS compliant and Halogen Free.
- 10) S-prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.

DEVICE MARKING AND ORDERING INFORMATION

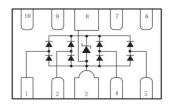
Device	Marking	Package	Shipping	
S-LRC1043-04DT1G	59	DFN-2510	3000/Tape&Reel	

S-LRC1043-04DT1G





DFN-2510 (Top view)



PIN CONFIGURATION

Jul. 2022



LESHAN RADIO COMPANY, LTD.

S-LRC1043-04DT1G

●ABSOLUTE MAXIMUM RATINGS

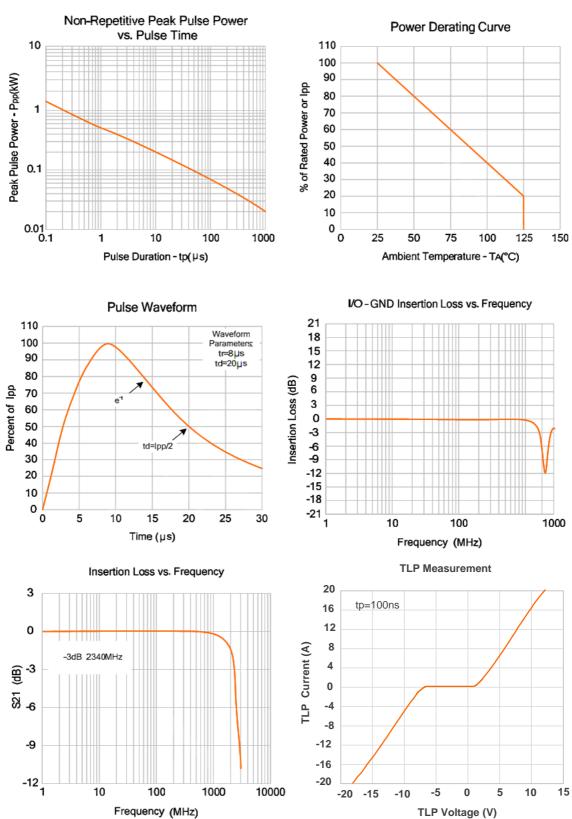
Parameter	Symbol	Limits	Unit
Peak Pulse Power(8/20us)	Ppp	70	W
Peak Pulse Current(8/20us)	IPP	5	Α
ESD per IEC 61000-4-2(Air)	VESD1	±15kV	kV
ESD per IEC 61000-4-2(Contact)	VESD2	±10kV	kV
Operating Temperature Range	Topr	-55 ~ +125	C
Storage Temperature Range	Tstg	-55 ~ +150	C

●ELECTRICAL CHARACTERISTICS (Ta= 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Reverse Working Voltage	VRWM	_	_	3.3	V	Any I/O pin to GND
Reverse Breakdown Voltage	VBR	5.6	Ι	_	V	It =1mA; Any I/O pin to GND
Reverse Leakage Current	IR	_	Ι	1	μA	VRWM =3V, T=25°C; Any I/O pin to GND
Positive Clamping Voltage	VC1	_	8	13	V	IPP=5A, tP=8/20µs; Positive pulse; Any I/O pin to GND
Negative Clamping Voltage	VC2	_	1.8	_	V	IPP=1A, tP=8/20µs; Negative pulse; Any I/O pin to GND
Junction Capacitance Between Channel	CJ1	_	0.25	0.35	pF	VR=0V, f=1MHz; Between I/O pins
Junction Capacitance Between I/O And GND	CJ2	_	0.45	0.5	рF	VR=0V, f=1MHz; Any I/O pin to GND



S-LRC1043-04DT1G



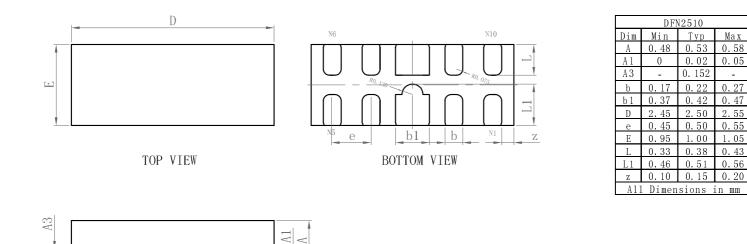
ELECTRICAL CHARACTERISTIC CURVES



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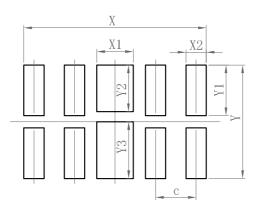
S-LRC1043-04DT1G

OUTLINE AND DIMENSIONS





SIDE VIEW



DFN2510	mm			
С	0.5			
Х	2.25			
X1	0.45			
X2	0.25			
Y	1.4			
Y 1	0.625			
¥2	0.575			
¥ 3	0.7			



DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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>>LRC(乐山无线电)